# NSN 5962-01-363-7534

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# Maximum Power Dissipation Rating:

1.1 watts

# **Operating Tempurature Range:**

-55.0 to 125.0 degrees celsius

# Storage Tempurature Range:

-65.0 to 150.0 degrees celsius

# Features Provided:

Burn in and monolithic and electrostatic sensitive and bipolar and programmed

## Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

# Input Circuit Pattern:

20 input

# Criticality Code Justification:

Nhcf

# Case Outline Source And Designator:

D-9 mil-m-38510

# **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## Memory Device Type:

Pal

# **Nuclear Hardness Critical Feature:**

Hardened

# Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

# Terminal Type And Quantity:

24 printed circuit

# Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

Fiig:

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